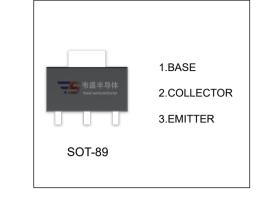


KTC4373 TRANSISTOR (NPN)

FEATURES

- Small Flat Package
- High Voltage Application
- High Voltage
- High Transition Frequency



MAXIMUM RATINGS (T_a=25℃ unless otherwise noted)

Symbol	Parameter	Value	Unit	
V _{CBO}	Collector-Base Voltage	120	V	
V _{CEO}	Collector-Emitter Voltage	120	V	
V _{EBO}	Emitter-Base Voltage	5	V	
Ic	Collector Current	800	mA	
Pc	Collector Power Dissipation	500	mW	
R _{θJA}	Thermal Resistance From Junction To Ambient 250 °C/V		°C/W	
T _J ,T _{stg}	Operation Junction and Storage Temperature Range	-55~+150	$^{\circ}$	

ELECTRICAL CHARACTERISTICS (T_a=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
Collector-base breakdown voltage	V _{(BR)CBO}	I _C = 1mA,I _E =0	120			V
Collector-emitter breakdown voltage	V _{(BR)CEO}	I _C =10mA,I _B =0	120			V
Emitter-base breakdown voltage	V _{(BR)EBO}	I _E =1mA,I _C =0	5			V
Collector cut-off current	I _{CBO}	V _{CB} =120V,I _E =0			100	nA
Emitter cut-off current	I _{EBO}	V _{EB} =5V,I _C =0			100	nA
DC current gain	h _{FE}	V _{CE} =5V, I _C =100mA	80		240	
Collector-emitter saturation voltage	V _{CE(sat)}	I _C =500mA,I _B =50mA			1	V
Base-emitter voltage	V_{BE}	V _{CE} =5V, I _C =500mA			1	V
Collector output capacitance	C _{ob}	V _{CB} =10V,I _E =0, f=1MHz			30	pF
Transition frequency	f _T	VcE=5V,Ic= 500mA		120		MHz

CLASSIFICATION OF h_{FE}

RANK	0	Υ
RANGE	80 - 160	120 - 240
MARKING	СО	CY